

Gp # 284



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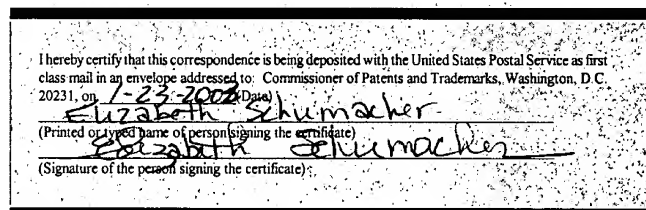
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Charles W. Pearce
Serial No.: 09/755,826
Filed: January 4, 2001
Title: A METHOD OF MANUFACTURING A Laterally Diffused METAL OXIDE SEMICONDUCTOR DEVICE
Grp./A.U.: 2813
Examiner: Chen, Jack S.

Honorable Commissioner of Patents
Washington, D.C. 20231



Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed October 24, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

(1) Kindly rewrite Claim 6 as follows:

6. (Amended) The method as recited in Claim 5 wherein diffusing the second dopant includes diffusing a P-type dopant having an implant dose ranging from about $1E13$ atoms/cm² to about $1E14$ atoms/cm².

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